

isc Silicon NPN RF Transistor

2SC4227

DESCRIPTION

- Low Noise
- NF = 1.4 dB TYP., @V_{CE} = 3 V, I_C = 7 mA, f = 1.0 GHz
- High Gain
 - \mid S_{21e} \mid 2 = 12 dB TYP. @V_{CE} = 3 V, I_C = 7 mA, f = 1.0 GHz
- 100% tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

• Designed for VHF, UHF low noise amplifier.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)					
SYMBOL	PARAMETER	VALUE	UNIT		
V _{CBO}	Collector-Base Voltage	20	V		
V _{CEO}	Collector-Emitter Voltage	10	V		
V _{EBO}	Emitter-Base Voltage	1.5	V		
lc	Collector Current-Continuous	65	mA		
Pc	Collector Power Dissipation @T _c =25°C	0.15	W		
TJ	Junction Temperature	150	്റ		
T _{stg}	Storage Temperature Range	-65~150	°C		

SOT-323 package

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DIM	MIN	MAX
А	0.30	0.40
В	1.15	1.35
С	2.00	2.40
D	0.	65
H	1.80	2.20
K	0.80	1.00
М	0.10	0.25

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ELECTRICAL CHARACTERISTICS

 $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
I _{CBO}	Collector Cutoff Current	V _{CB} = 10V; I _E = 0			0.8	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 1V; I _C = 0			0.8	μA
h _{FE}	DC Current Gain	Ic= 7mA ; V _{CE} = 3V	40		240	
f _T	Current-Gain—Bandwidth Product	I _C = 7mA ; V _{CE} = 3V	4.5	7.0		GHz
Cre	Feed-Back Capacitance	I _E = 0 ; V _{CB} = 3V;f= 1.0MHz		0.45	0.9	pF
S _{21e} ²	Insertion Power Gain	I _C = 7mA ; V _{CE} = 3V;f= 1.0GHz	10	12		dB
NF	Noise Figure	I _C = 7mA ; V _{CE} = 3V;f= 1.0GHz		1.4	2.7	dB

h_{FE} Classification

Class	R33	R34	R35
Marking	R33	R34	R35
h _{FE}	40-90	70-150	110-240

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